# **AN79Nxx Series**

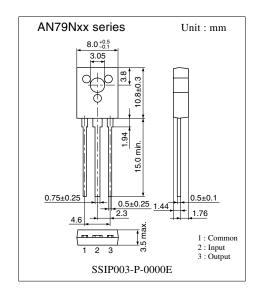
# 3-pin negative output voltage regulator (300 mA type)

#### Overview

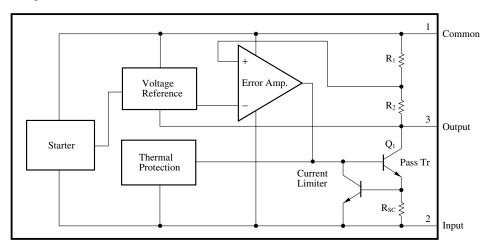
The AN79Nxx series is a 3-pin, fixed negative output type monolithic voltage regulator. Stabilized fixed output voltage is obtained from unstable DC input voltage without using any external component IC. 12 types of output voltage are available: -4V, -5V, -6V, -7V, -8V, -9V, -10V, -12V, -15V, -18V, -20V and -24V. They can be used widely in power circuits with current capacity of up to 300mA.

#### ■ Features

- No external components
- Output voltage: -4V, -5V, -6V, -7V, -8V, -9V, -10V, -12V, -15V, -18V, -20V, -24V
- Built-in overcurrent limit circuit
- Built-in thermal overload protection circuit
- Built-in ASO (area of safe operation) protection circuit



#### ■ Block Diagram



# ■ Absolute Maximum Ratings at T<sub>a</sub> = 25°C

Parameter	Symbol	Rating	Unit
To make and the are	37	-35 *1	V
Input voltage	$V_{I}$	-40 * <sup>2</sup>	V
Power dissipation	$P_{\mathrm{D}}$	8 *3	W
Operating ambient temperature	$T_{opr}$	-20 to +80	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

<sup>\*1</sup> AN79N04, AN79N05, AN79N06, AN79N07, AN79N08, AN79N09, AN79N10, AN79N12, AN79N15, AN79N18

# ■ Electrical Characteristics at $T_a = 25$ °C

#### • AN79N04 (-4V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	-3.84	-4	-4.16	V
Output voltage tolerance	Vo	$V_{\rm I} = -6 \text{ to } -25 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-3.8		-4.2	V
Line regulation	REG <sub>IN</sub>	$V_I = -6 \text{ to } -25 \text{V}, T_j = 25^{\circ}\text{C}$		9	40	mV
Line regulation	KEOIN	$V_I = -7 \text{ to } -17V, T_j = 25^{\circ}C$		4	20	mV
Load regulation	REG <sub>I</sub>	$I_0 = 1 \text{ to } 300\text{mA}, T_j = 25^{\circ}\text{C}$		20	80	mV
	KEUL	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$		10	40	mV
Bias current	$I_{Bias}$	$T_j = 25^{\circ}C$		3	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -7 \text{ to } -25 \text{V}, T_j = 25 ^{\circ}\text{C}$	_	_	0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	$V_{no}$	f = 10Hz to 100kHz		100		μV
Ripple rejection ratio	RR	$V_I = -7 \text{ to } -17V, I_O = 50\text{mA},$ f = 120Hz	60	_		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_0 = 200 \text{mA}, T_j = 25^{\circ}\text{C}$		1.1	_	V
Output short-circuit current	I <sub>O(Short)</sub>	$V_I = -35V, T_j = 25^{\circ}C$		10	_	mA
Peak output current	I <sub>O(Peak)</sub>	$T_j = 25^{\circ}C$		500	_	mA
Output voltage temperature coefficient	$\Delta V_{O}/T_{a}$	$I_O = 5mA$		- 0.4	_	mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}$ C means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

<sup>\*2</sup> AN79N20, AN79N24

<sup>\*3</sup> Follow the derating curve. When T<sub>j</sub> exceeds 150°C, the internal circuit cuts off the output.

Note 2) Unless otherwise specified,  $V_1 = -9V$ ,  $I_0 = 100 \text{mA}$ ,  $C_1 = 2\mu\text{F}$ ,  $C_0 = 1\mu\text{F}$  and  $T_j = 0$  to  $125^{\circ}\text{C}$ 

#### • AN79N05 (-5V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	$V_{O}$	$T_j = 25^{\circ}C$	-4.8	-5	-5.2	V
Output voltage tolerance	$V_{O}$	$V_{\rm I} = -7 \text{ to } -25 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-4.75		-5.25	V
Line regulation	REG <sub>IN</sub>	$V_I = -7 \text{ to } -25V, T_j = 25^{\circ}C$		10	50	mV
Line regulation	KEGIN	$V_I = -8 \text{ to } -18V, T_j = 25^{\circ}C$		5	30	mV
I and manufaction	REG <sub>L</sub>	$I_0 = 1 \text{ to } 300\text{mA}, T_j = 25^{\circ}\text{C}$		20	100	mV
Load regulation	KEUL	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$		10	50	mV
Bias current	$I_{\mathrm{Bias}}$	$T_j = 25^{\circ}C$		3	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -8 \text{ to } -25 \text{V}, T_j = 25^{\circ}\text{C}$		_	0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	$V_{no}$	f = 10Hz to 100kHz		125		μV
Ripple rejection ratio	RR	$V_I = -8 \text{ to } -18V, I_O = 50\text{mA},$ f = 120Hz	60	_		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_0 = 200 \text{mA}, T_j = 25^{\circ}\text{C}$		1.1		V
Output short-circuit current	I <sub>O(Short)</sub>	$V_I = -35V, T_j = 25^{\circ}C$		10	_	mA
Peak output current	I <sub>O(Peak)</sub>	$T_j = 25^{\circ}C$		500		mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5mA$		- 0.4		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}\text{C}$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

#### • AN79N06 (-6V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	$V_{O}$	$T_j = 25^{\circ}C$	-5.75	-6	-6.25	V
Output voltage tolerance	$V_{\rm o}$	$V_{\rm I} = -8 \text{ to } -25 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-5.7		-6.3	V
Line regulation	$REG_{IN}$	$V_I = -8 \text{ to } -25 \text{V}, T_j = 25^{\circ} \text{C}$		11	60	mV
Line regulation	KEOIN	$V_I = -9 \text{ to } -19V, T_j = 25^{\circ}C$		6	40	mV
T 1 12	DEC	$I_0 = 1 \text{ to } 300\text{mA}, T_j = 25^{\circ}\text{C}$		20	120	mV
Load regulation	$REG_L$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$	_	10	60	mV
Bias current	$I_{\text{Bias}}$	$T_j = 25^{\circ}C$		3	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -9 \text{ to } -25 \text{V}, T_j = 25^{\circ}\text{C}$			0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$	_		0.1	mA
Output noise voltage	$V_{no}$	f = 10Hz to 100kHz		150		μV
Ripple rejection ratio	RR	$V_I = -9 \text{ to } -19V, I_O = 50\text{mA},$ f = 120Hz	60			dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$		1.1		V
Output short-circuit current	$I_{O(Short)}$	$V_I = -35V, T_j = 25^{\circ}C$		10	_	mA
Peak output current	I <sub>O(Peak)</sub>	$T_j = 25^{\circ}C$		500	_	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 200 \text{mA}$		- 0.4		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_I = -10V$ ,  $I_O = 100$ mA,  $C_I = 2\mu$ F,  $C_O = 1\mu$ F and  $T_j = 0$  to  $125^{\circ}$ C

Note 2) Unless otherwise specified,  $V_I = -11V$ ,  $I_O = 100mA$ ,  $C_I = 2\mu F$ ,  $C_O = 1\mu F$  and  $T_j = 0$  to  $125^{\circ}C$ 

#### • AN79N07 (-7V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	$V_{O}$	$T_j = 25^{\circ}C$	-6.7	-7	-7.3	V
Output voltage tolerance	$V_{O}$	$V_{\rm I} = -9 \text{ to } -25 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-6.65		-7.35	V
Line regulation	REG <sub>IN</sub>	$V_I = -9 \text{ to } -25V, T_j = 25^{\circ}C$		12	70	mV
Line regulation	KLOIN	$V_I = -10 \text{ to } -20 \text{V}, T_j = 25^{\circ} \text{C}$		7	35	mV
I and manufaction	REG <sub>I</sub>	$I_0 = 1 \text{ to } 300\text{mA}, T_j = 25^{\circ}\text{C}$		20	140	mV
Load regulation	$KEO_L$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$		10	70	mV
Bias current	$I_{Bias}$	$T_j = 25^{\circ}C$		3	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -10 \text{ to } -25 \text{V}, T_j = 25^{\circ}\text{C}$		_	0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	$V_{no}$	f = 10Hz to 100kHz		175		μV
Ripple rejection ratio	RR	$V_I = -10 \text{ to } -20\text{V}, I_O = 50\text{mA},$ f = 120Hz	59	_		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_0 = 200 \text{mA}, T_j = 25^{\circ}\text{C}$		1.1	_	V
Output short-circuit current	$I_{O(Short)}$	$V_I = -35V, T_j = 25^{\circ}C$		10	_	mA
Peak output current	I <sub>O(Peak)</sub>	$T_j = 25^{\circ}C$		500	_	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5mA$		- 0.5	_	mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}$ C means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

#### • AN79N08 (-8V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	-7.7	-8	-8.3	V
Output voltage tolerance	Vo	$V_{\rm I} = -10.5 \text{ to } -25 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-7.6		-8.4	V
Line regulation	REG <sub>IN</sub>	$V_I = -10.5 \text{ to } -25 \text{V}, T_j = 25^{\circ}\text{C}$		13	80	mV
Line regulation	KEOIN	$V_I = -11 \text{ to } -21 \text{V}, T_j = 25^{\circ}\text{C}$		8	40	mV
T 1 1	$REG_L$	$I_0 = 1 \text{ to } 300 \text{mA}, T_j = 25^{\circ}\text{C}$		25	160	mV
Load regulation	KEUL	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$		10	80	mV
Bias current	$I_{Bias}$	$T_j = 25$ °C		3	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -10.5 \text{ to } -25 \text{V}, T_j = 25^{\circ}\text{C}$	_		0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	$V_{no}$	f = 10Hz to 100kHz		200		μV
Ripple rejection ratio	RR	$V_I = -11.5 \text{ to } -21.5 \text{V}, I_O = 50 \text{mA},$ f = 120Hz	59	_		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_O = 200 \text{mA}, T_j = 25^{\circ}\text{C}$		1.1		V
Output short-circuit current	I <sub>O(Short)</sub>	$V_I = -35V, T_j = 25^{\circ}C$		10		mA
Peak output current	I <sub>O(Peak)</sub>	$T_j = 25^{\circ}C$	_	500	_	mA
Output voltage temperature coefficient	$\Delta V_{O}/T_{a}$	$I_O = 5mA$		- 0.6		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_1 = -14V$ ,  $I_0 = 100$ mA,  $C_1 = 2\mu$ F,  $C_0 = 1\mu$ F and  $T_j = 0$  to  $125^{\circ}$ C

Note 2) Unless otherwise specified,  $V_I = -12V$ ,  $I_O = 100$ mA,  $C_I = 2\mu$ F,  $C_O = 1\mu$ F and  $T_i = 0$  to 125°C

## • AN79N09 (-9V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	$V_{O}$	$T_j = 25^{\circ}C$	-8.65	-9	-9.35	V
Output voltage tolerance	Vo	$V_{\rm I} = -11.5 \text{ to } -26 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-8.55		-9.45	V
Line regulation	REG <sub>IN</sub>	$V_I = -11.5 \text{ to } -26V, T_j = 25^{\circ}C$		14	80	mV
Line regulation	KEOIN	$V_I = -12 \text{ to } -22 \text{V}, T_j = 25^{\circ}\text{C}$		9	50	mV
I and manufaction	REG	$I_0 = 1 \text{ to } 300\text{mA}, T_j = 25^{\circ}\text{C}$		25	180	mV
Load regulation	KEGL	$I_0 = 5 \text{ to } 200 \text{mA}, T_j = 25^{\circ}\text{C}$		10	90	mV
Bias current	$I_{Bias}$	$T_j = 25^{\circ}C$		3	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -11.5 \text{ to } -26V, T_j = 25^{\circ}C$		_	0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	$V_{no}$	f = 10Hz to 100kHz		225		μV
Ripple rejection ratio	RR	$V_I = -12 \text{ to } -22 \text{V}, I_O = 50 \text{mA},$ f = 120Hz	58	_		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_O = 200 \text{mA}, T_j = 25^{\circ}\text{C}$		1.1		V
Output short-circuit current	I <sub>O(Short)</sub>	$V_I = -35V, T_j = 25^{\circ}C$		10	_	mA
Peak output current	I <sub>O(Peak)</sub>	$T_j = 25$ °C		500		mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5mA$		- 0.6		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}$ C means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

#### • AN79N10 (-10V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	-9.6	-10	-10.4	V
Output voltage tolerance	Vo	$V_{\rm I} = -12.5 \text{ to } -27 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-9.5		-10.5	V
Line regulation	REG <sub>IN</sub>	$V_I = -12.5 \text{ to } -27 \text{V}, T_j = 25^{\circ}\text{C}$		15	80	mV
Line regulation	KEOIN	$V_I = -13 \text{ to } -23 \text{V}, T_j = 25^{\circ}\text{C}$		10	50	mV
Load manufaction	$REG_L$	$I_0 = 1 \text{ to } 300 \text{mA}, T_j = 25^{\circ}\text{C}$		25	200	mV
Load regulation	KEUL	$I_0 = 5 \text{ to } 200 \text{mA}, T_j = 25^{\circ}\text{C}$		10	100	mV
Bias current	$I_{Bias}$	$T_j = 25^{\circ}C$		3.0	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -12.5 \text{ to } -27 \text{V}, T_j = 25^{\circ}\text{C}$			0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	$V_{no}$	f = 10Hz to 100kHz		250		μV
Ripple rejection ratio	RR	$V_I = -13 \text{ to } -23 \text{V}, I_O = 50 \text{mA},$ f = 120Hz	58	_		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_0 = 200 \text{mA}, T_j = 25^{\circ}\text{C}$		1.1	_	V
Output short-circuit current	I <sub>O(Short)</sub>	$V_I = -35V, T_j = 25^{\circ}C$		10	_	mA
Peak output current	I <sub>O(Peak)</sub>	$T_j = 25^{\circ}C$		500	_	mA
Output voltage temperature coefficient	$\Delta V_{O}/T_{a}$	$I_O = 5mA$	_	- 0.7	_	mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_1 = -15V$ ,  $I_0 = 100$ mA,  $C_1 = 2\mu$ F,  $C_0 = 1\mu$ F and  $T_j = 0$  to  $125^{\circ}$ C

Note 2) Unless otherwise specified,  $V_1 = -16V$ ,  $I_0 = 100$ mA,  $C_1 = 2\mu$ F,  $C_0 = 1\mu$ F and  $T_j = 0$  to  $125^{\circ}$ C

#### • AN79N12 (-12V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	$V_{O}$	$T_j = 25^{\circ}C$	-11.5	-12	-12.5	V
Output voltage tolerance	$V_{O}$	$V_{\rm I} = -14.5 \text{ to } -30 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-11.4		-12.6	V
Line regulation	REG <sub>IN</sub>	$V_I = -14.5 \text{ to } -30V, T_j = 25^{\circ}C$		15	80	mV
Line regulation	KLOIN	$V_I = -15 \text{ to } -25 \text{V}, T_j = 25^{\circ}\text{C}$		10	50	mV
I and manufaction	REG	$I_0 = 1 \text{ to } 300 \text{mA}, T_j = 25^{\circ}\text{C}$		25	240	mV
Load regulation	KEUL	$I_0 = 5 \text{ to } 200 \text{mA}, T_j = 25^{\circ}\text{C}$		10	120	mV
Bias current	$I_{\mathrm{Bias}}$	$T_j = 25^{\circ}C$		3	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -14.5 \text{ to } -30\text{V}, T_j = 25^{\circ}\text{C}$			0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	$V_{no}$	f = 10Hz to 100kHz		300		μV
Ripple rejection ratio	RR	$V_I = -15 \text{ to } -25 \text{V}, \ I_O = 50 \text{mA}, \\ f = 120 \text{Hz}$	57	_		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_O = 200 \text{mA}, T_j = 25^{\circ}\text{C}$		1.1	_	V
Output short-circuit current	I <sub>O(Short)</sub>	$V_I = -35V, T_j = 25^{\circ}C$		10	_	mA
Peak output current	I <sub>O(Peak)</sub>	$T_j = 25$ °C		500	_	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5mA$		- 0.8	_	mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored. Note 2) Unless otherwise specified,  $V_I = -19V$ ,  $I_O = 100mA$ ,  $C_I = 2\mu F$ ,  $C_O = 1\mu F$  and  $T_j = 0$  to  $125^{\circ}C$ 

#### • AN79N15 (-15V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	$V_{O}$	$T_j = 25^{\circ}C$	-14.4	-15	-15.6	V
Output voltage tolerance	$V_{O}$	$V_{\rm I} = -17.5 \text{ to } -30 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-14.25		-15.75	V
Line regulation	REG <sub>IN</sub>	$V_I = -17.5 \text{ to } -30\text{V}, T_j = 25^{\circ}\text{C}$		16	80	mV
Line regulation	KEGIN	$V_I = -18 \text{ to } -28 \text{V}, T_j = 25^{\circ}\text{C}$		11	50	mV
Load regulation	$REG_L$	$I_0 = 1 \text{ to } 300\text{mA}, T_j = 25^{\circ}\text{C}$		25	240	mV
Load regulation	KEUL	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$		10	120	mV
Bias current	$I_{Bias}$	$T_j = 25^{\circ}C$	_	3	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -17.5 \text{ to } -30 \text{V}, T_j = 25^{\circ}\text{C}$			0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	$V_{no}$	f = 10Hz to 100kHz	_	375	_	μV
Ripple rejection ratio	RR	$V_I = -18 \text{ to } -28 \text{V}, I_O = 50 \text{mA}, f = 120 \text{Hz}$	56			dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_0 = 200 \text{mA}, T_j = 25^{\circ}\text{C}$		1.1		V
Output short-circuit current	I <sub>O(Short)</sub>	$V_I = -35V, T_j = 25^{\circ}C$		10		mA
Peak output current	$I_{O(Peak)} \\$	$T_j = 25^{\circ}C$		500		mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_0 = 5mA$		- 0.9		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}$ C means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_1 = -23V$ ,  $I_0 = 100$ mA,  $C_1 = 2\mu$ F,  $C_0 = 1\mu$ F and  $T_j = 0$  to  $125^{\circ}$ C

#### • AN79N18 (-18V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	$V_{O}$	$T_j = 25^{\circ}C$	-17.3	-18	-18.7	V
Output voltage tolerance	$V_{O}$	$V_{\rm I} = -21 \text{ to } -33 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-17.1		-18.9	V
Line regulation	$REG_{IN}$	$V_I = -21 \text{ to } -33 \text{V}, T_j = 25^{\circ}\text{C}$		18	80	mV
Line regulation	KEUIN	$V_I = -22 \text{ to } -32 \text{V}, T_j = 25^{\circ}\text{C}$		13	50	mV
Load regulation	REG <sub>L</sub>	$I_0 = 1 \text{ to } 300\text{mA}, T_j = 25^{\circ}\text{C}$		30	300	mV
Load regulation	KEUL	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$		10	150	mV
Bias current	$I_{Bias}$	$T_j = 25$ °C		3	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -21 \text{ to } -33 \text{V}, T_j = 25^{\circ}\text{C}$		-	0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$		_	0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to 100kHz		450		μV
Ripple rejection ratio	RR	$V_I = -22 \text{ to } -32 \text{V}, I_O = 50 \text{mA},$ f = 120Hz	55	_		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_0 = 200 \text{mA}, T_j = 25^{\circ}\text{C}$		1.1	_	V
Output short-circuit current	I <sub>O(Short)</sub>	$V_I = -35V, T_j = 25^{\circ}C$		10	_	mA
Peak output current	$I_{O(Peak)} \\$	$T_j = 25^{\circ}C$		500		mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_0 = 5mA$		-1		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

#### • AN79N20 (-20V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	$V_{O}$	$T_j = 25^{\circ}C$	-19.2	-20	-20.8	V
Output voltage tolerance	$V_{O}$	$V_{\rm I} = -23 \text{ to } -35 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-19		-21	V
Line regulation	$REG_{IN}$	$V_I = -23 \text{ to } -35 \text{V}, T_j = 25^{\circ}\text{C}$		19	80	mV
Line regulation	KLOIN	$V_I = -24 \text{ to } -34 \text{V}, T_j = 25^{\circ}\text{C}$		14	70	mV
Load regulation	REG <sub>I</sub>	$I_0 = 1 \text{ to } 300 \text{mA}, T_j = 25^{\circ}\text{C}$		30	300	mV
Load regulation	KEUL	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$		10	150	mV
Bias current	$I_{\mathrm{Bias}}$	$T_j = 25^{\circ}C$		3	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -23 \text{ to } -35 \text{V}, T_j = 25 ^{\circ}\text{C}$			0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to 100kHz		500		μV
Ripple rejection ratio	RR	$V_I = -24 \text{ to } -34 \text{V}, I_O = 50 \text{mA},$ f = 120Hz	54	_		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_0 = 200 \text{mA}, T_j = 25^{\circ}\text{C}$		1.1		V
Output short-circuit current	$I_{O(Short)}$	$V_I = -35V, T_j = 25^{\circ}C$		10		mA
Peak output current	I <sub>O(Peak)</sub>	$T_j = 25^{\circ}C$		500		mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5mA$		-1	_	mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_I = -27V$ ,  $I_O = 100$ mA,  $C_I = 2\mu$ F,  $C_O = 1\mu$ F and  $T_i = 0$  to  $125^{\circ}$ C

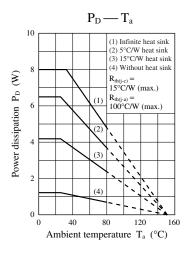
Note 2) Unless otherwise specified,  $V_I = -29V$ ,  $I_O = 100mA$ ,  $C_I = 2\mu F$ ,  $C_O = 1\mu F$  and  $T_j = 0$  to  $125^{\circ}C$ 

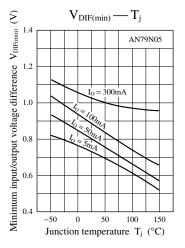
#### • AN79N24 (-24V type)

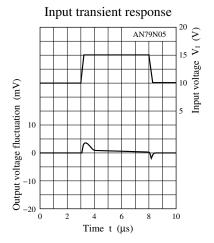
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	$V_{O}$	$T_j = 25^{\circ}C$	-23	-24	-25	V
Output voltage tolerance	$V_{O}$	$V_{\rm I} = -27 \text{ to } -38 \text{V}, I_{\rm O} = 5 \text{ to } 200 \text{mA}$	-22.8		-25.2	V
Line regulation	REG <sub>IN</sub>	$V_I = -27 \text{ to } -38V, T_j = 25^{\circ}C$		20	80	mV
		$V_I = -27 \text{ to } -37 \text{V}, T_j = 25^{\circ}\text{C}$	_	15	70	mV
Load regulation	REG <sub>L</sub>	$I_0 = 1 \text{ to } 300\text{mA}, T_j = 25^{\circ}\text{C}$		30	300	mV
		$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$		10	150	mV
Bias current	$I_{Bias}$	$T_j = 25^{\circ}C$		3	5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = -27 \text{ to } -38 \text{V}, T_j = 25^{\circ}\text{C}$			0.5	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 5 \text{ to } 200\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	$V_{no}$	f = 10Hz to 100kHz		600	_	μV
Ripple rejection ratio	RR	$V_I = -28 \text{ to } -38 \text{V}, I_O = 50 \text{mA},$ f = 120Hz	54			dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$I_0 = 200 \text{mA}, T_j = 25^{\circ}\text{C}$		1.1		V
Output short-circuit current	I <sub>O(Short)</sub>	$V_I = -35V, T_j = 25^{\circ}C$		10	_	mA
Peak output current	$I_{O(Peak)}$	$T_j = 25^{\circ}C$		500		mA
Output voltage temperature coefficient	$\Delta V_{O}/T_{a}$	$I_0 = 5mA$		-1		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

#### ■ Main Characteristics

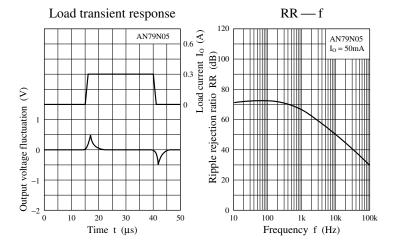




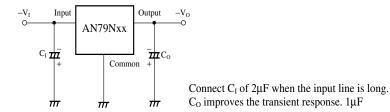


Note 2) Unless otherwise specified,  $V_1 = -33V$ ,  $I_0 = 100$ mA,  $C_1 = 2\mu$ F,  $C_0 = 1\mu$ F and  $T_j = 0$  to  $125^{\circ}$ C

#### ■ Main Characteristics (continued)



#### ■ Basic Regulator Circuit



#### ■ Usage Notes

## 1. Cautions for a basic circuit

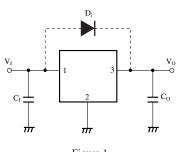


Figure 1

- C<sub>I</sub>: When a wiring from a smoothing circuit to a three-pin regulator is long, it is likely to oscillate at output. A capacitor of 0.1µF to 0.47µF should be connected near an input pin.
- $C_0$ : Deadly needed to prevent from oscillation (0.33 $\mu$ F to 1.0 $\mu$ F). It is recommended to use a capacitor of a small internal impedance (ex. tantalum capacitor) when using it under a low temperature.
  - When any sudden change of load current is likely to occur, connect an electrolytic capacitor of 10µF to 100µF to improve a transitional response of output voltage.
- Di: Normally unnecessary. But add it in the case that there is a residual voltage at the output capacitor Co even after switching off the supply power because a current is likely to flow into an output pin of the IC and damage the IC.

#### ■ Usage Notes (continued)

#### 2. Other caution items

#### 1) Short-circuit between the input pin and GND pin

If the input pin is short-circuitted to GND or is cut off when a large capacitance capacitor has been connected to the IC's load, a voltage of a capacitor connected to an output pin is applied between input/output of the IC and this likely results in damage of the IC. It is necessary, therefore, to connect a diode, as shown in figure 2, to counter the reverse bias between input/output pins.

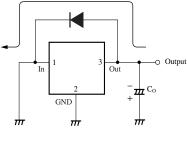


Figure 2

#### 2) Floating of GND pin

If a GND pin is made floating in an operating mode, an unstabilized input voltage is outputted. In this case, a thermal protection circuit inside the IC does not normally operate. In this state, if the load is short-circuited or overloaded, it is likely to damage the IC.

#### ■ Application Circuit Example

